

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	305	(wire wiring line conductor) near4 (copper adj alloy) with (thick thickness thicker thin thinner)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:20
L2	3	(wire wiring line conductor) near4 (copper adj alloy) with (thick thickness thicker thin thinner) with magnesium	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:24
L3	31	(wire wiring line conductor) near4 (copper adj alloy) with magnesium	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:37
L5	39	(wire wiring line conductor gate electrode) near4 (copper adj alloy) with magnesium	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:42
L6	2	((wire wiring line conductor gate electrode) near4 (copper adj alloy)) with (magnesium) with ((concentration atomic) near4 (percent "%"))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:39
L7	2	((wire wiring line conductor gate electrode) near4 (copper adj alloy)) with (magnesium with (concentration (atomic near4 (percent "%"))))	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:41
L8	2	(wire wiring line conductor gate electrode) near4 (copper adj alloy) with magnesium with concentration	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:42
L9	2	(wire wiring line conductor gate electrode) near4 (copper adj alloy) with magnesium with atomic	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:43
L10	2	(wire wiring line conductor gate electrode) near4 (copper adj alloy) with magnesium with (atomic percent)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:43
L11	9	(wire wiring line conductor gate electrode) near4 (copper adj alloy) with magnesium with (atomic percent "%")	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:45

L12	6	(wire wiring line conductor gate electrode) near4 (copper near3 magnesium) with magnesium with (atomic percent "%")	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:47
L13	20	(wire wiring line conductor gate electrode diameter thick thickness) near4 (copper near3 copper) with magnesium	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 08:48